**TENTATIVE** 

TOSHIBA PHOTOCOUPLER GaAlAs IRED & PHOTO-TRIAC

# **TLP168J**

TRIAC DRIVE
PROGRAMMABLE CONTROLLERS
AC-OUTPUT MODULE
SOLID STATE RELAY

The TOSHIBA MINI FLAT COUPLER TLP168J is a small outline coupler, suitable for surface mount assembly.

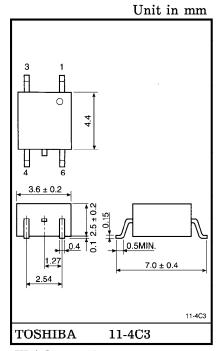
The TLP168J consists of a photo triac, optically coupled to a GaA $\ell$ As infrared emitting diode.

• Zero-Voltage Crossing Turn-on

Peak Off-State Voltage : 600V (MIN.)
 Trigger LED Current : 3mA (MAX.)
 On-State Current : 70mA (MAX.)
 Isolation Voltage : 2500Vrms (MIN.)

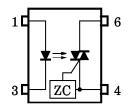
#### MAXIMUM RATINGS ( $Ta = 25^{\circ}C$ )

CHARACTERISTIC			SYMBOL	RATING	UNIT
	Forward Current	${ m I_F}$	20	mA	
	Forward Current I (Ta\ge 25°C)	ΔI <sub>F</sub> /°C	-0.2	mA/°C	
LED	Peak Forward Current (100 µs pulse, 100 pps)		$I_{\mathrm{FP}}$	1	A
	Reverse Voltage	$v_{R}$	5	V	
	Junction Temperat	$\mathrm{T_{j}}$	125	°C	
	Off-State Output T Voltage	$v_{ m DRM}$	600	V	
	On-State RMS	Ta=25°C	т	70	
OR	Current	Ta=70°C	IT (RMS)	40	mA
DETECTOR	On-State Current Derating (Ta≥25°C)		ΔI <sub>T</sub> /°C	-0.67	mA/°C
DEJ	Peak On-State Cur (100µs Pulse, 120p	$I_{ ext{TP}}$	2	A	
	Peak Nonrepetitive Surge Current (Pw=10ms, DC=10%)		$I_{TSM}$	1.2	A
	Junction Temperat	$\mathrm{T_{j}}$	115	°C	
Sto	orage Temperature	T <sub>stg</sub> -55~125		°C	
Op	erating Temperatu	T <sub>opr</sub> -40~100		$^{\circ}\mathrm{C}$	
Le	ad Soldering Tempe	$T_{sol}$	260	°C	
	lation Voltage C, 1min., R.H.≦60	BV <sub>S</sub> 2500		Vrms	



Weight: 0.09g

#### PIN CONFIGURATIONS



1 : ANODE 3 : CATHODE 4 : TERMINAL 1 6 : TERMINAL 2

(Note) Device considered a two terminal device: Pins 1 and 3 shorted together and pins 4 and 6 shorted together.

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

961001EBC2

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$v_{AC}$			240	Vac
Forward Current	$\mathbf{I_F}$	4.5	6	7.5	mA
Peak On-State Current	$I_{ ext{TP}}$	_	_	1	A
Operating Temperature	$T_{ m opr}$	-10	_	85	°C

## INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	$ m V_{f F}$	$I_{ m F} = 10 { m mA}$	1.2	1.4	1.7	V
	Reverse Current	${ m I}_{ m R}$	$V_{\mathbf{R}} = 3V$	_	_	10	$\mu$ A
	Capacitance	${ m C_T}$	V=0, f=1MHz	_	30		рF
OR	Peak Off-State Current	$I_{ m DRM}$	$V_{DRM} = 600V$	_	10	1000	nA
	Peak On-State Voltage	$ m V_{TM}$	$I_{TM} = 70 \text{mA}$	_	1.7	2.8	V
CT(	Holding Current	$ m I_{ m H}$	_	_	0.6	_	mA
DETE	Critical Rate of Rise of Off- State Voltage	dv/dt	V <sub>in</sub> =240Vrms, Ta=85°C	200	500	_	V/μs
	Critical Rate of Rise of Commutating Voltage	dv / dt (c)	$V_{in}$ =60Vrms, I <sub>T</sub> =15mArms	_	0.2	_	V/μs

## COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	$I_{ ext{FT}}$	$V_{\mathrm{T}} = 6V$	_	_	3	mA
Inhibit Voltage	$ m V_{IH}$	I <sub>F</sub> =Rated I <sub>F</sub> T	_	_	50	V
Leakage in Inhibited State	$I_{ m IH}$	$I_{ m F}\!=\!{ m Rated}I_{ m FT} \ { m V}_{ m T}\!=\!{ m Rated}{ m V}_{ m DRM}$		200	600	$\mu$ <b>A</b>
Capacitance (Input to Output)	$c_{S}$	$V_S=0$ , f=1MHz	<b>—</b>	0.8		pF
Isolation Resistance	$R_{\mathbf{S}}$	$V_S = 500V, R.H. \le 60\%$	$5 \times 10^{10}$	1014	_	Ω
	$_{ m BV_S}$	AC, 1 minute	2500	_	<del></del>	7.7
Isolation Voltage		AC, 1 second, in oil	_	5000	_	Vrms
		DC, 1 minute, in oil	_	5000		Vdc

Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

The products described in this document are subject to foreign exchange and foreign trade control laws.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

The information contained herein is subject to change without notice.

